74ALVCH16374

Low-Voltage 16-Bit D-Type Flip-Flop with Bus Hold 1.8/2.5/3.3 V
(3−State, Non−Inverting)

The 74ALVCH16374 is an advanced performance, non−inverting 16−bit D−type flip−flop. It is designed for very high−speed, very low−power operation in 1.8 V, 2.5 V or 3.3 V systems. The VCXH16374 is byte controlled, with each byte functioning identically, but independently. Each byte has separate Output Enable and Clock Pulse inputs. These control pins can be tied together for full 16−bit operation.

The 74ALVCH16374 consists of 16 edge−triggered flip−flops with individual D−type inputs and 3.6 V−tolerant 3−state outputs. The clocks (CPn) and Output Enables ($\overline{\text{OEn}}$) are common to all flip−flops within the respective byte. The flip−flops will store the state of individual D inputs that meet the setup and hold time requirements on the LOW−to−HIGH Clock (CP) transition. With the $\overline{\text{OE}}$ LOW, the contents of the flip−flops are available at the outputs. When the $\overline{\text{OE}}$ is HIGH, the outputs go to the high impedance state. The $\overline{\text{OE}}$ input level does not affect the operation of the flip−flops. The data inputs include active bushold circuitry, eliminating the need for external pull−up resistors to hold unused or floating inputs at a valid logic state.

- Designed for Low Voltage Operation: V_{CC} = 1.65 − 3.6 V
- 3.6 V Tolerant Inputs and Outputs
- High Speed Operation: 3.6 ns max for 3.0 to 3.6 V
  4.5 ns max for 2.3 to 2.7 V
  7.8 ns max for 1.65 to 1.95 V
- Static Drive: ±24 mA Drive at 3.0 V
  ±12 mA Drive at 2.3 V
  ±4 mA Drive at 1.65 V
- Supports Live Insertion and Withdrawal
- Includes Active Bushold to Hold Unused or Floating Inputs at a Valid Logic State
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0 V[†]
- Near Zero Static Supply Current in All Three Logic States (40 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds ±250 mA @ 125°C
- ESD Performance: Human Body Model >2000V; Machine Model >200V
- Second Source to Industry Standard 74ALVCH16374

†To ensure the outputs activate in the 3−state condition, the output enable pins should be connected to V_{CC} through a pull−up resistor. The value of the resistor is determined by the current sinking capability of the output connected to the $\overline{\text{OE}}$ pin.

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MARKING DIAGRAM

**TSSOP−48
DT SUFFIX
CASE 1201**

48

74ALVCH16374DT
AWLYYWW

1
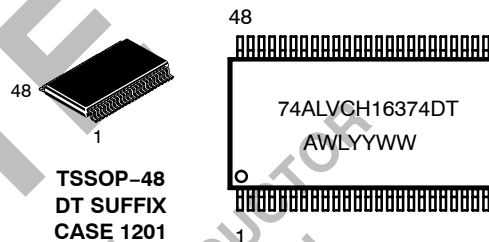
A   = Assembly
Location
WL   = Wafer Lot
YY   = Year
WW   = Work Week

PIN NAMES

Pins	Function
$\overline{\text{OEn}}$	Output Enable Inputs
CPn	Clock Pulse Inputs
D0–D15	Inputs
O0–O15	Outputs

ORDERING INFORMATION

Device	Package	Shipping
74ALVCH16374DTR	TSSOP	2500 / Reel

74ALVCH16374

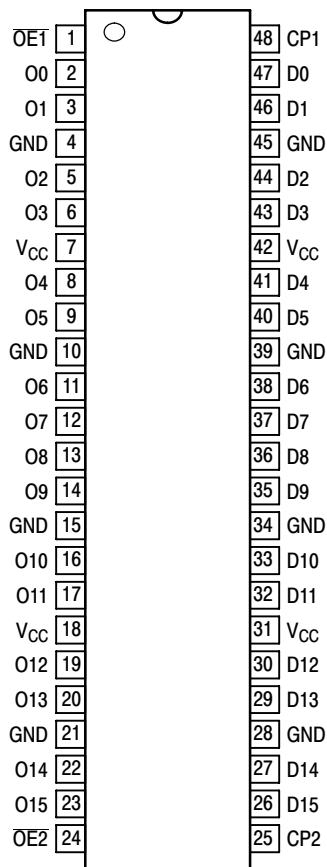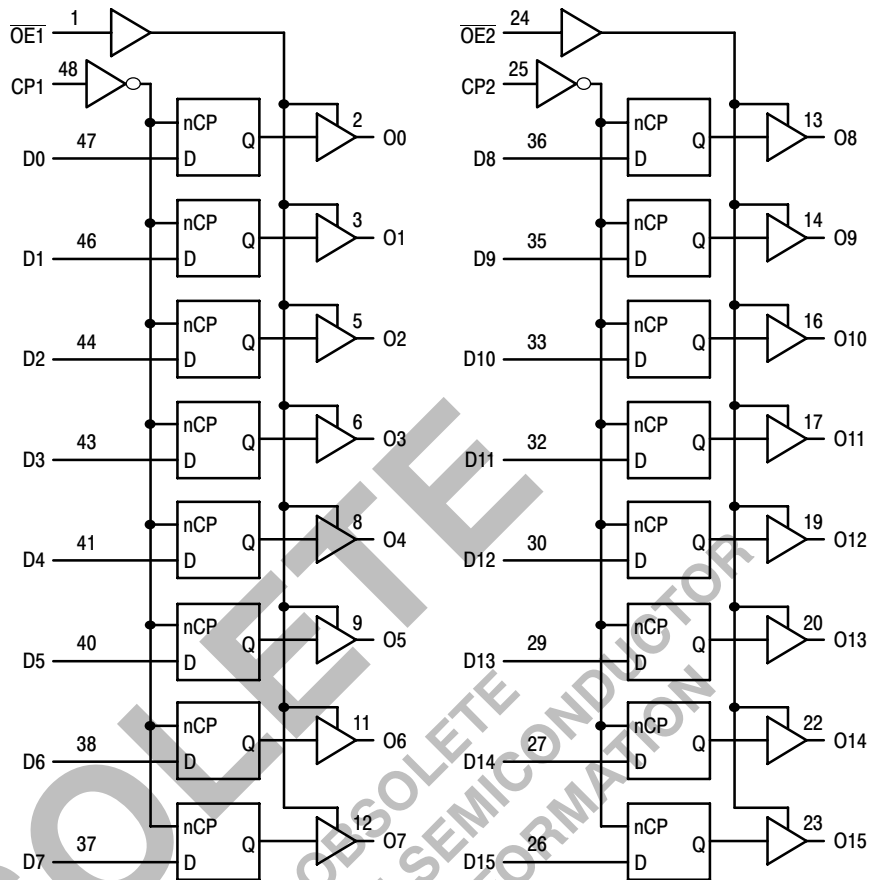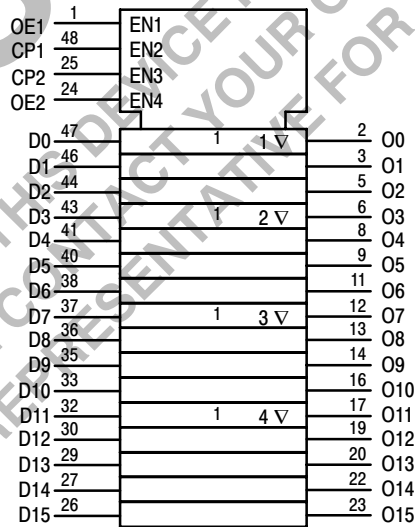**Figure 1. 48−Lead Pinout**
(Top View)

Figure 2. Logic Diagram

Figure 3. IEC Logic Diagram

Inputs			Outputs	Inputs			Outputs
CP1	$\overline{OE1}$	D0:7	O0:7	CP2	$\overline{OE2}$	D8:15	O8:15
↑	L	H	H	↑	L	H	H
↑	L	L	L	↑	L	L	L
X	L	X	O0	X	L	X	O0
X	H	X	Z	X	H	X	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; ↑ Low−to−High Transition; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs. O0 = No Change.

MAXIMUM RATINGS (Note 1)

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		-0.5 to $+4.6$	V
V_I	DC Input Voltage		-0.5 to $+4.6$	V
V_O	DC Output Voltage		-0.5 to $+4.6$	V
I_{IK}	DC Input Diode Current	$V_I < GND$	-50	mA
I_{OK}	DC Output Diode Current	$V_O < GND$	-50	mA
I_O	DC Output Sink Current		± 50	mA
I_{CC}	DC Supply Current per Supply Pin		± 100	mA
I_{GND}	DC Ground Current per Ground Pin		± 100	mA
T_{STG}	Storage Temperature Range		-65 to $+150$	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		$+150$	°C
θ_{JA}	Thermal Resistance (Note 2)		90	°C/W
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 30 to 35	UL 94 V–O @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	>2000 >200 N/A	V
$I_{LATCH-UP}$	Latch–Up Performance	Above V_{CC} and Below GND at 125°C (Note 6)	± 250	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm–by–1 inch, 2–ounce copper trace with no air flow.
3. Tested to EIA/JESD22–A114–A.
4. Tested to EIA/JESD22–A115–A.
5. Tested to JESD22–C101–A.
6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage	Operating Data Retention Only	2.3 1.5	3.6 3.6	V
V_I	Input Voltage	(Note 7)	-0.5	3.6	V
V_O	Output Voltage	(Active State) (3–State)	0 0	3.6 3.6	V
T_A	Operating Free–Air Temperature		-40	$+85$	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate	$V_{CC} = 2.5$ V $\pm$ 0.2 V $V_{CC} = 3.0$ V $\pm$ 0.3 V	0 0	20 10	ns/V

7. Unused inputs may not be left open. All inputs must be tied to a high–logic voltage level or a low–logic input voltage level.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	$T_A = -40°C$ to $+85°C$ Min	Max	Unit
V_{IH}	HIGH Level Input Voltage (Note 8)	$1.65\ V \leq V_{CC} < 2.3\ V$	$0.65 \times V_{CC}$		V
		$2.3\ V \leq V_{CC} \leq 2.7\ V$	1.7		
		$2.7\ V < V_{CC} \leq 3.6\ V$	2.0		
V_{IL}	LOW Level Input Voltage (Note 8)	$1.65\ V \leq V_{CC} < 2.3\ V$		$0.35 \times V_{CC}$	V
		$2.3\ V \leq V_{CC} \leq 2.7\ V$		0.7	
		$2.7\ V < V_{CC} \leq 3.6\ V$		0.8	
V_{OH}	HIGH Level Output Voltage	$1.65\ V \leq V_{CC} \leq 3.6\ V;\ I_{OH} = -100\ \mu A$	$V_{CC} - 0.2$		V
		$V_{CC} = 1.65\ V;\ I_{OH} = -4\ mA$	1.2		
		$V_{CC} = 2.3\ V;\ I_{OH} = -6\ mA$	2.0		
		$V_{CC} = 2.3\ V;\ I_{OH} = -12\ mA$	1.7		
		$V_{CC} = 2.7\ V;\ I_{OH} = -12\ mA$	2.2		
		$V_{CC} = 3.0\ V;\ I_{OH} = -12\ mA$	2.4		
		$V_{CC} = 3.0\ V;\ I_{OH} = -24\ mA$	2.0		
V_{OL}	LOW Level Output Voltage	$1.65\ V \leq V_{CC} \leq 3.6\ V;\ I_{OL} = 100\ \mu A$		0.2	V
		$V_{CC} = 1.65\ V;\ I_{OL} = 4\ mA$		0.45	
		$V_{CC} = 2.3\ V;\ I_{OL} = 6\ mA$		0.4	
		$V_{CC} = 2.3\ V;\ I_{OL} = 12\ mA$		0.7	
		$V_{CC} = 2.7\ V;\ I_{OL} = 12\ mA$		0.4	
		$V_{CC} = 3.0\ V;\ I_{OL} = 24\ mA$		0.55	
I_I	Input Leakage Current	$1.65\ V \leq V_{CC} \leq 3.6\ V;\ 0\ V \leq V_I \leq 3.6\ V$		± 5.0	μA
$I_{I(HOLD)}$	Minimum Bus–hold Input Current	$V_{CC} = 3.6\ V;\ V_{IN} = 0$ to $3.6\ V$		± 500	μA
		$V_{CC} = 3.0\ V,\ V_{IN} = 0.8\ V$	75		
		$V_{CC} = 3.0\ V,\ V_{IN} = 2.0\ V$	-75		
		$V_{CC} = 2.3\ V,\ V_{IN} = 0.7\ V$	45		
		$V_{CC} = 2.3\ V,\ V_{IN} = 1.7\ V$	-45		
		$V_{CC} = 1.65\ V,\ V_{IN} = 0.58\ V$	25		
		$V_{CC} = 1.65\ V,\ V_{IN} = 1.07\ V$	-25		
I_{OZ}	3–State Output Current	$1.65\ V \leq V_{CC} \leq 3.6\ V;\ 0\ V \leq V_O \leq 3.6\ V;\ V_I = V_{IH}$ or V_{IL}		± 10	μA
I_{OFF}	Power–Off Leakage Current	$V_{CC} = 0\ V;\ V_I$ or $V_O = 3.6\ V$		10	μA
I_{CC}	Quiescent Supply Current (Note 9)	$1.65\ V \leq V_{CC} \leq 3.6\ V;\ V_I = GND$ or V_{CC}		40	μA
		$1.65\ V \leq V_{CC} \leq 3.6\ V;\ 3.6\ V \leq V_I,\ V_O \leq 3.6\ V$		± 40	
ΔI_{CC}	Increase in I_{CC} per Input	$2.7\ V < V_{CC} \leq 3.6\ V;\ V_{IH} = V_{CC} - 0.6\ V$		750	μA

8. These values of V_I are used to test DC electrical characteristics only.
9. Outputs disabled or 3–state only.

AC CHARACTERISTICS (Note 10; $t_R = t_F = 2.0$ ns; $C_L = 30$ pF; $R_L = 500~\Omega$)

Symbol	Parameter	Wave-form	Limits $T_A = -40°C$ to $+85°C$						Unit
			V_{CC} = 3.0 V to 3.6 V		V_{CC} = 2.3 V to 2.7 V		V_{CC} = 1.65 V to 1.95 V		
			Min	Max	Min	Max	Min	Max	
f_{max}	Clock Pulse Frequency	1	250		200		100		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to On	1	1.0 1.0	3.6 3.6	1.0 1.0	4.5 4.5	1.0 1.0	7.8 7.8	ns
t_{PZH} t_{PZL}	Output Enable Time to High and Low Level	2	1.0 1.0	4.7 4.7	1.0 1.0	6.0 6.0	1.0 1.0	9.2 9.2	ns
t_{PHZ} t_{PLZ}	Output Disable Time From High and Low Level	2	1.0 1.0	4.1 4.1	1.0 1.0	5.1 5.1	1.5 1.5	6.8 6.8	ns
t_s	Setup Time, High or Low Dn to CP	3	1.5		0.5		2.5		ns
t_h	Hold Time, High or Low Dn to CP	3	1.0		0.5		1.0		ns
t_w	CP Pulse Width, High	3	1.5		0.5		4.0		ns
t_{OSHL} t_{OSLH}	Output-to-Output Skew (Note 11)			0.5 0.5		0.5 0.5		0.75 0.75	ns

10. For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.
11. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	Note 12	6	pF
C_{OUT}	Output Capacitance	Note 12	7	pF
C_{PD}	Power Dissipation Capacitance	Note 12, 10 MHz	20	pF

12. V_{CC} = 1.8, 2.5 or 3.3 V; V_I = 0 V or V_{CC}.
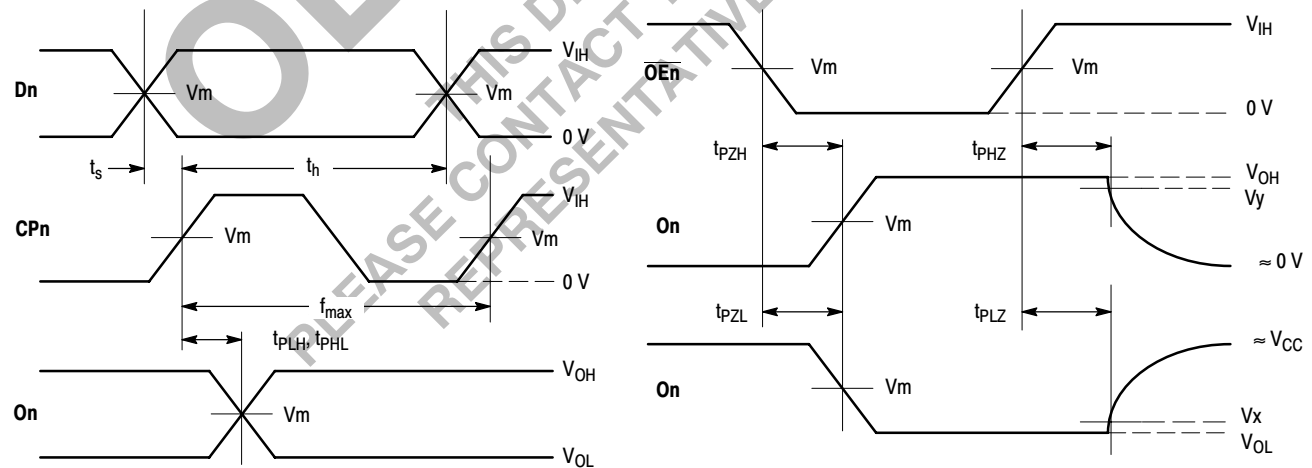
WAVEFORM 1 – PROPAGATION DELAYS, SETUP AND HOLD TIMES
$t_R = t_F = 2.0$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns

WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES
$t_R = t_F = 2.0$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns

Figure 4. AC Waveforms
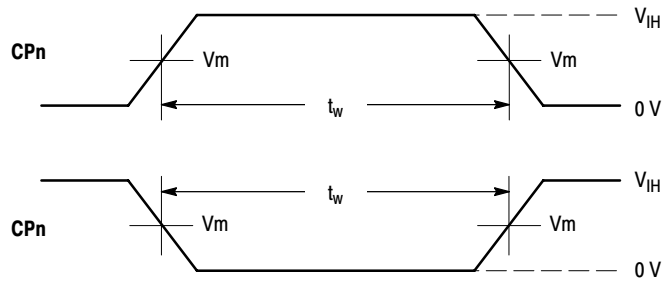
WAVEFORM 3 – PULSE WIDTH

$t_R = t_F = 2.0$ ns (or fast as required) from 10% to 90%

Figure 5. AC Waveforms

Symbol	V_{CC}		
	3.3 V $\pm$0.3 V	**2.5 V $\pm$0.2 V**	**1.8 V $\pm$0.15 V**
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_m	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_x	$V_{OL} + 0.3$ V	$V_{OL} + 0.15$ V	$V_{OL} + 0.15$ V
V_y	$V_{OH} - 0.3$ V	$V_{OH} - 0.15$ V	$V_{OH} - 0.15$ V
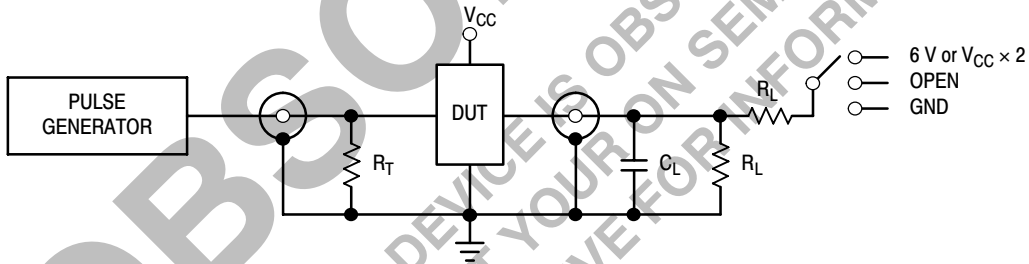
TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6 V at $V_{CC} = 3.3 \pm 0.3$ V; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2$V; 1.8 V $\pm$0.15 V
t_{PZH}, t_{PHZ}	GND

$C_L = 50$ pF for $V_{CC} = 3.0 \pm 0.3$ V
$R_L = 500$ Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 6. Test Circuit

74ALVCH16374
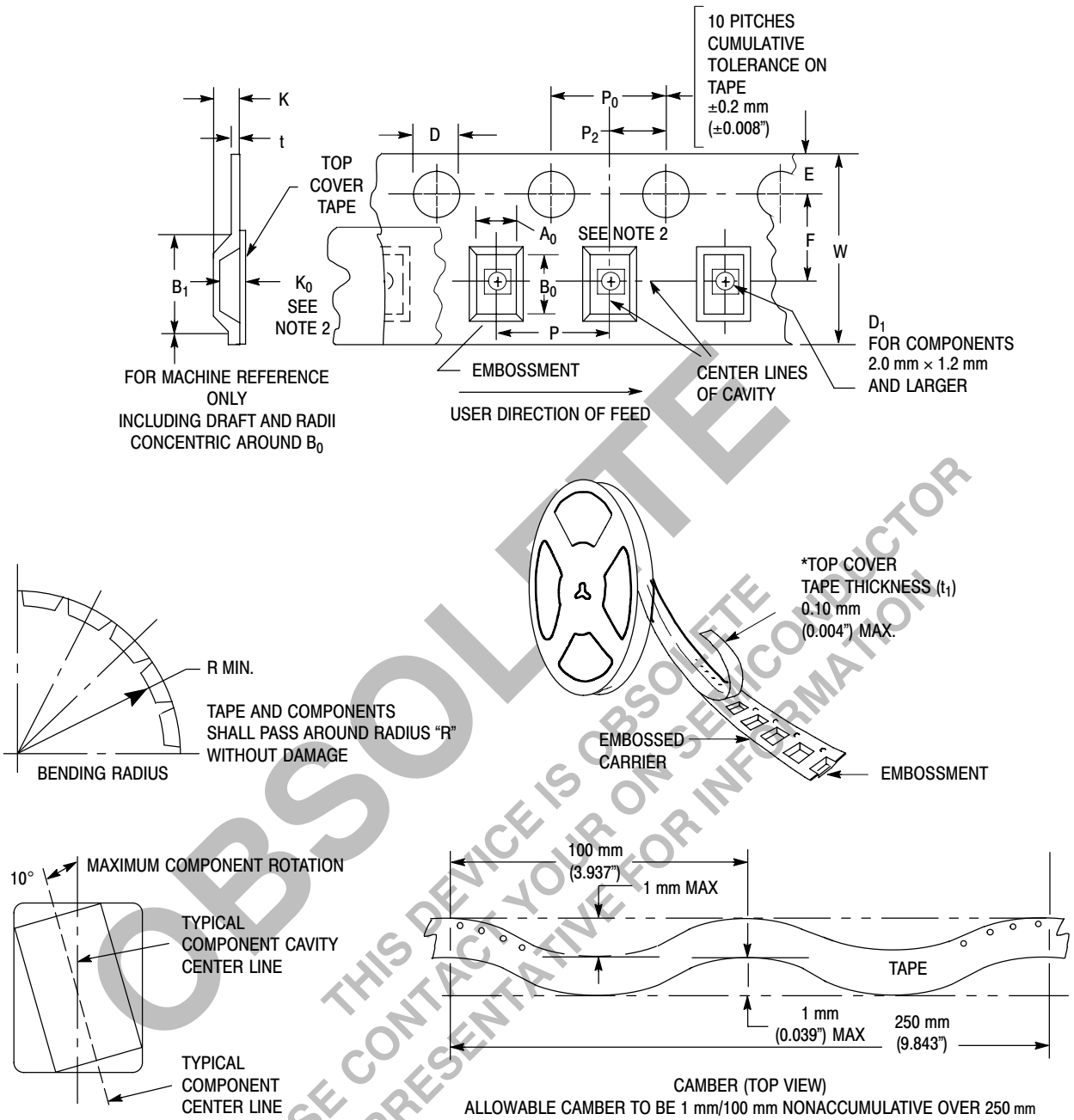
Figure 7. Carrier Tape Specifications

EMBOSSED CARRIER DIMENSIONS (See Notes 1 and 2)

Tape Size	B₁ Max	D	D₁	E	F	K	P	P₀	P₂	R	T	W
24mm	20.1mm (0.791")	1.5 + 0.1mm –0.0 (0.059 +0.004" –0.0)	1.5mm Min (0.060")	1.75 ±0.1 mm (0.069 ±0.004")	11.5 ±0.10 mm (0.453 ±0.004")	11.9 mm Max (0.468")	16.0 ±0.1 mm (0.63 ±0.004")	4.0 ±0.1 mm (0.157 ±0.004")	2.0 ±0.1 mm (0.079 ±0.004")	30 mm (1.18")	0.6 mm (0.024")	24.3 mm (0.957")

13. Metric Dimensions Govern–English are in parentheses for reference only.
14. A_0, B_0, and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity.
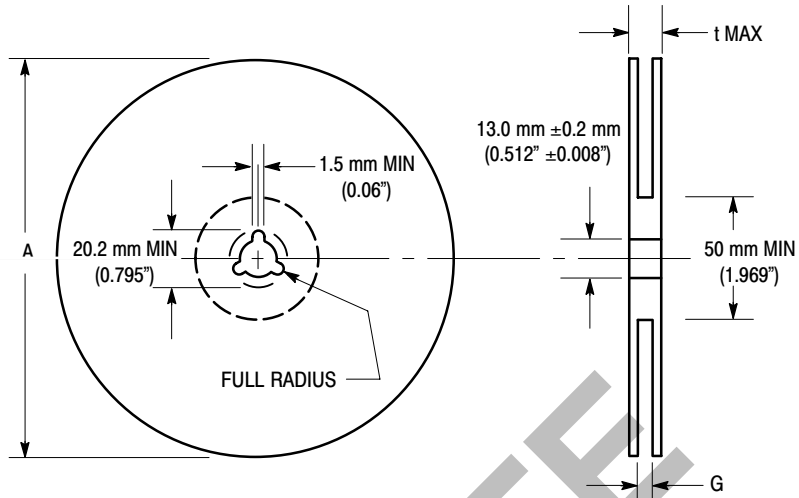
Figure 8. Reel Dimensions

REEL DIMENSIONS

Tape Size	A Max	G	t Max
24 mm	360 mm (14.173")	24.4 mm + 2.0 mm, −0.0 (0.961" + 0.078", −0.00)	30.4 mm (1.197")
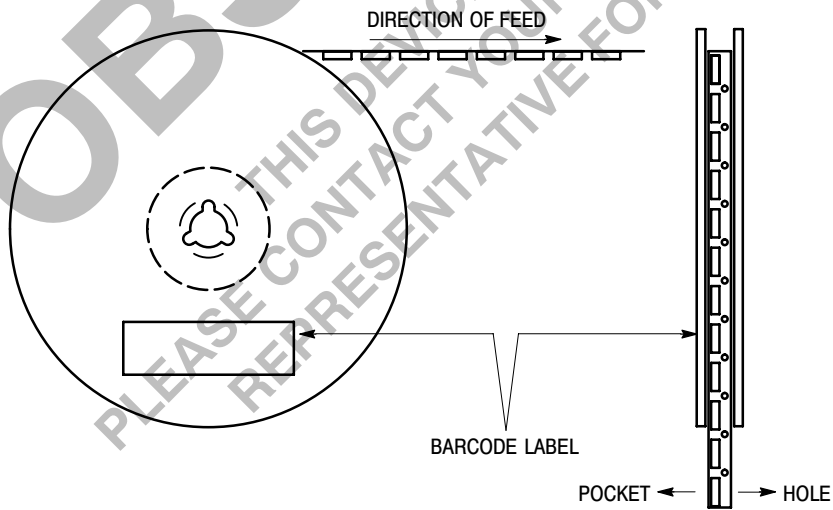
Figure 9. Reel Winding Direction

CAVITY
TAPE

TOP TAPE

TAPE TRAILER
(Connected to Reel Hub)
NO COMPONENTS
160 mm MIN

COMPONENTS

TAPE LEADER
NO COMPONENTS
400 mm MIN

DIRECTION OF FEED
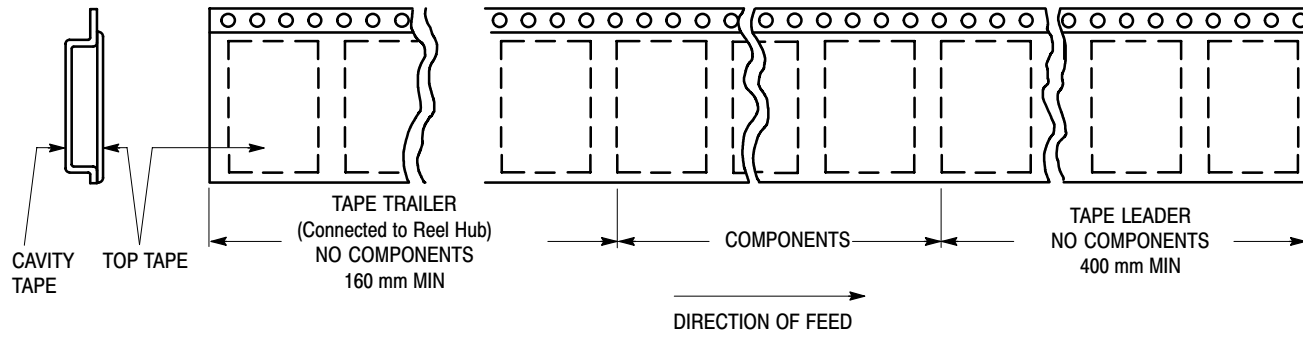
Figure 10. Tape Ends for Finished Goods

User Direction of Feed
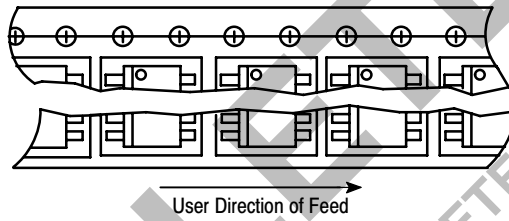
Figure 11. Reel Configuration

K

F

L

48 Leads

G
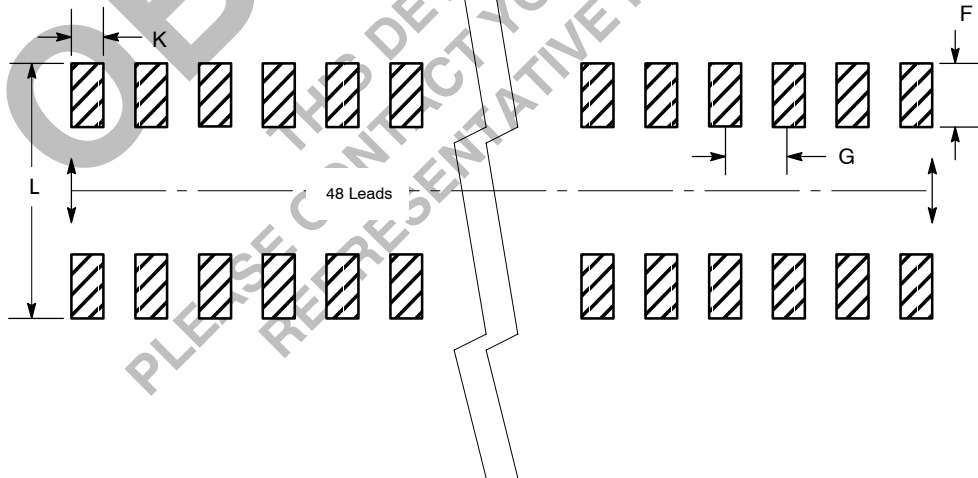
Figure 12. Package Footprint

PACKAGE DIMENSIONS

TSSOP
DT SUFFIX
CASE 1201–01
ISSUE A
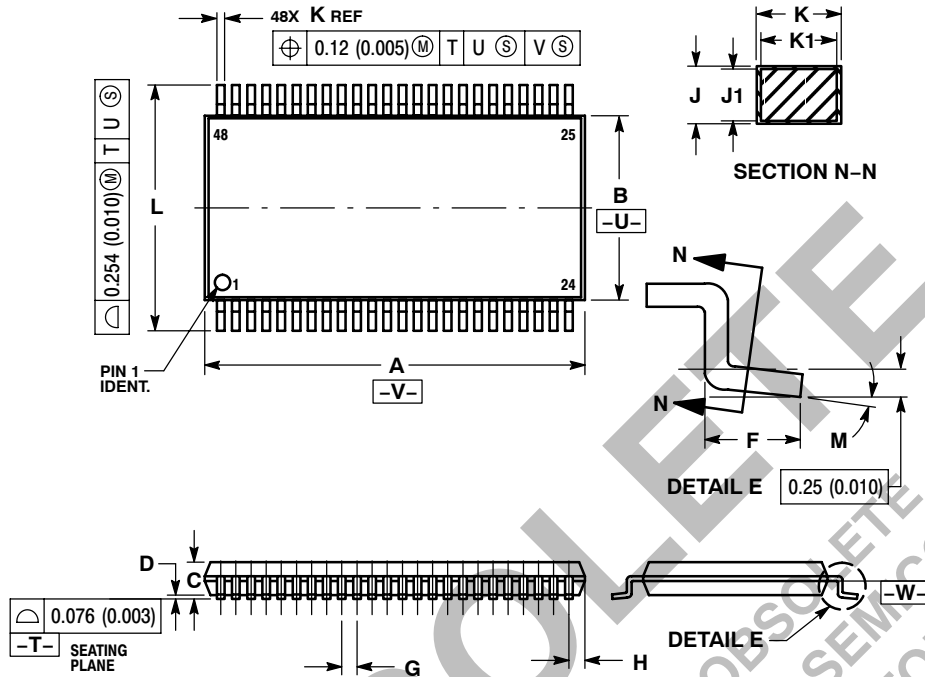
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	12.40	12.60	0.488	0.496
B	6.00	6.20	0.236	0.244
C	---	1.10	---	0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.50 BSC		0.0197 BSC	
H	0.37	---	0.015	---
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.17	0.27	0.007	0.011
K1	0.17	0.23	0.007	0.009
L	7.95	8.25	0.313	0.325
M	0 °	8 °	0 °	8 °

74ALVCH16374/D